NSN 5962-01-310-8696

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Body Lengt	h:
0.440 inches	
Body Width	
0.285 inches	
Body Heigh	t:
0.085 inches	
	ower Dissipation Rating:
332.8 milliwa	
Operating T	empurature Range:
	degrees celsius
	npurature Range:
	degrees celsius
Features Pro	
Monolithic ar	nd w/open collector and bipolar and programmable
Inclosure M	
Ceramic	
Inclosure C	onfiguration:
Flat pack	
Output Logi	c Form:
Transistor-tra	ansistor logic
Input Circui	t Pattern:
6 input	
Case Outlin	e Source And Designator:
F-5 mil-m-38	510
Terminal Su	Irface Treatment:
Solder	
Voltage Rat	ing And Type Per Characteristic:
7.0 volts pov	wer source
Time Rating	Per Chacteristic:
50.00 nanos	econds propagation delay time, low to high level output and 50.00 nanoseconds propagation delay time, high to low level
output	
Memory Dev	vice Type:
Rom	
Test Data D	ocument:
96906-mil-st	d-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Ty	pe And Quantity:
16 flat leads	
Shelf Life:	
N/a	
Unit Of Mea	sure:
Demilitariza	tion:
Yes - demil/r	nli

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